

# A dissipatively stabilized Mott insulator of photons

Ruichao Ma, Brendan Saxberg , Clai Owens , Nelson Leung , Yao Lu ,  
Jonathan Simon & David I. Schuster

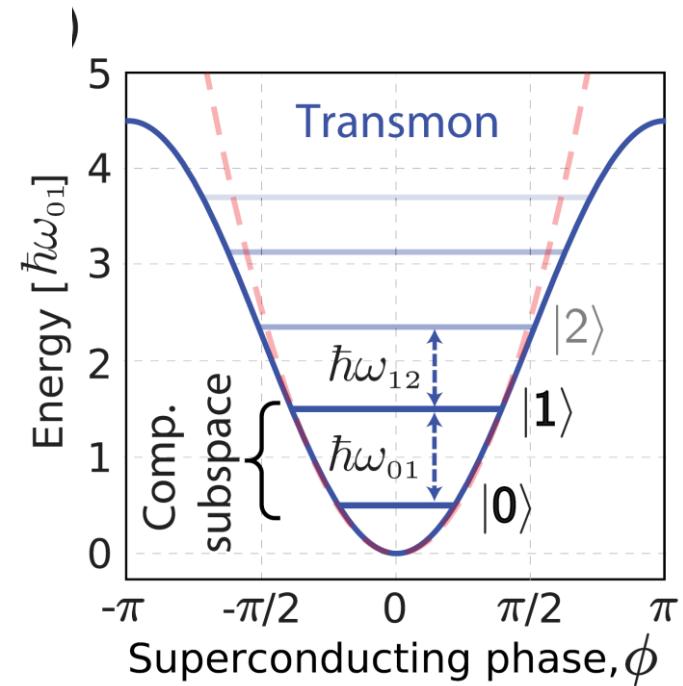
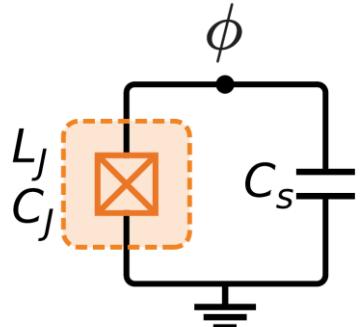
# Motivation

- Thermalization of a condensed matter system, when in contact with a reservoir
- Anderson 1958: Some Quantum states (strongly disordered, isolated) (sometimes) do not self thermalize (Many-Body-Localization (MBL))
- MBL is non ergodic: State stays close to its initial state for infinite amount of time
- Problem: It is very hard to determine the ordering dynamics of the Hamiltonian in this regime.
- Synthetic quantum materials can be used to investigate this behaviour (Quantum simulation)
- Photonic systems offer tunability, strong correlation and long coherence time.



	2D electron gas	Ultracold atoms	Microwave photons					
Trapped in:			 Microwave resonator SC qubit					
Ionic lattice		Optical lattice						
Interactions mediated by:								
Coulomb potential		Van der Waals potential						
Interaction energy scale	80 K $\sim h \times 2$ THz	20 nK $\sim h \times 400$ Hz	10 mK $\sim h \times 200$ MHz					
Coherence time	2 ns	10 s	100 $\mu$ s					
Interaction to coherence ratio	$\sim 3,000$	$\sim 4,000$	$\sim 20,000$					
Strength of the platform	Direct application in real world, clean-room fabrication	Scalable, optical manipulation/readout	Arbitrary connectivity, reservoir engineering					
Jacopo Carusotto, Andrew A. Houck , Alicia J. Kollár, Pedram Roushan, David I. Schuster and Jonathan Simon, „Photonic materials in circuit quantum electrodynamics“, (2020)								
Adiabatic preparation								
Spectroscopic assembly								
Dissipative stabilization								
Pros	<p>• Harnesses ability to prepare low-entropy unentangled state • Agnostic to target state</p>							
Cons	<p>• Sensitive to small gaps at quantum phase transition • Sensitive to symmetries</p> <p>• Hardly applicable beyond few particles</p>							
• Agnostic to target state • Efficient for gapped manybody states								
• Potentially challenging for gapless states • Sensitive to transport speed of defects • Hard to model theoretically								

# From LC-circuit to Transmon qubit



Energy of an electronic device  $E(t) = \int_{-\infty}^t V(t')I(t')dt'$

## Capacitance

$$I = C\dot{V}$$

$$Q(t) = \int_{-\infty}^t I(t')dt'$$

$$n = \frac{Q}{2e}$$

$$E_C = \frac{e^2}{2C} \quad \rightarrow \quad E_C = \frac{e^2}{2(C_S + C_J)}$$

$$Q = C\dot{\Phi}$$

## Inductance

$$V = L\dot{I}$$

$$\Phi(t) = \int_{-\infty}^t I(t')dt'$$

$$\phi = \frac{2\pi\Phi}{\Phi_0}$$

$$E_L = \frac{\Phi_0^2}{4\pi^2 C}$$

## Josephson junction

$$V = \frac{\hbar}{2e} \frac{d\phi}{dt}$$

$$I = I_{crit} \sin(\phi)$$

$$E_J = \frac{I_C \Phi_0}{2\pi}$$

$$E_J = E_J(\phi_e) = 2E'_J |\cos(\phi_e)|$$

$$H = 4E_C n^2 + \frac{1}{2}E_L \phi^2$$

$$H = \hbar\omega_r \left( a^\dagger a + \frac{1}{2} \right) = \hbar\omega_r \left( m + \frac{1}{2} \right) \quad \omega_r = \frac{\sqrt{8E_L E_C}}{\hbar}$$



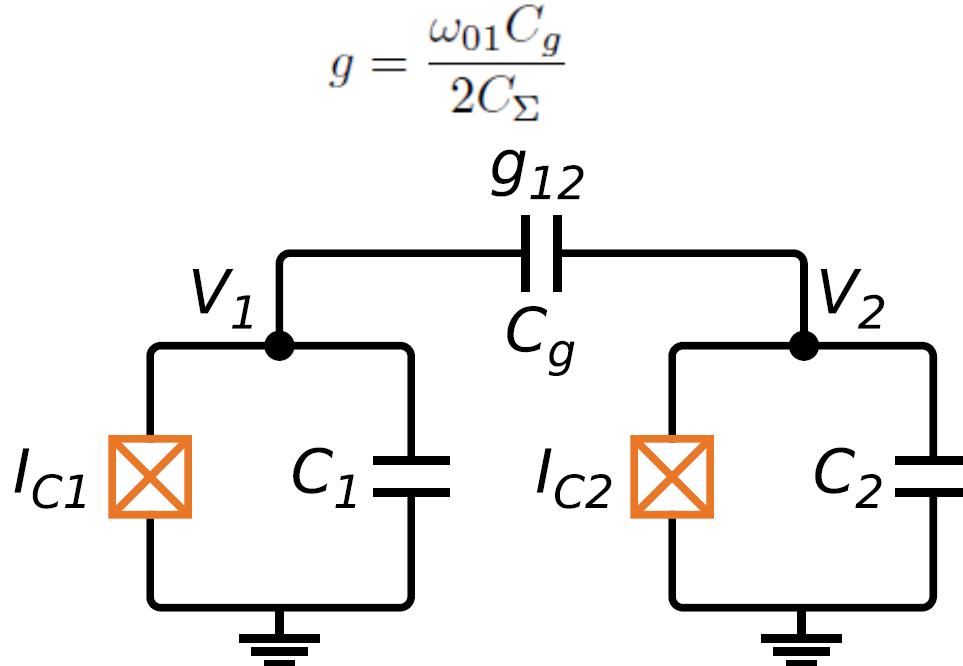
$$H = 4E_C n^2 - E_J \cos(\phi) \quad H = \sqrt{8E_C E_J} \left( m + \frac{1}{2} \right) - E_J - \frac{E_C}{12} (6m^2 + 6m + 3) \quad \alpha = E_{12} - E_{01} = -E_C$$

# Qubit coupling

$$\frac{H_{JC}}{\hbar} = \omega_r \left( m_r + \frac{1}{2} \right) + \omega_q \left( m_q + \frac{1}{2} \right) + g(a_q^\dagger a_r + a_q a_r^\dagger)$$

Coupling Hamiltonian for a qubit and a resonator

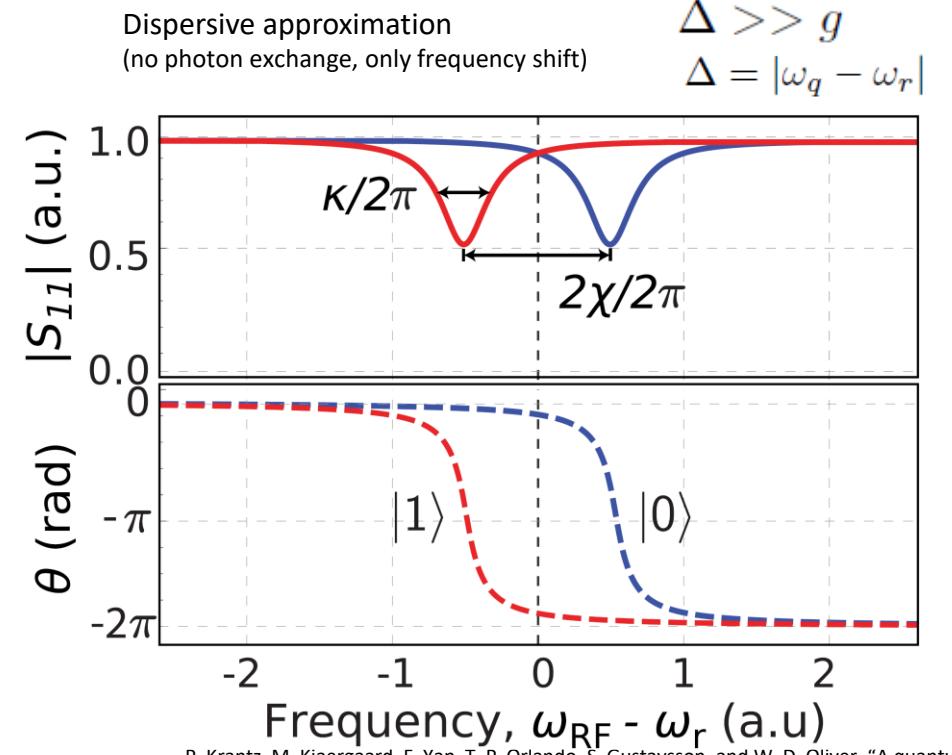
## Capacitative qubit coupling



$$a^\dagger |m\rangle = \sqrt{m+1} |m+1\rangle$$

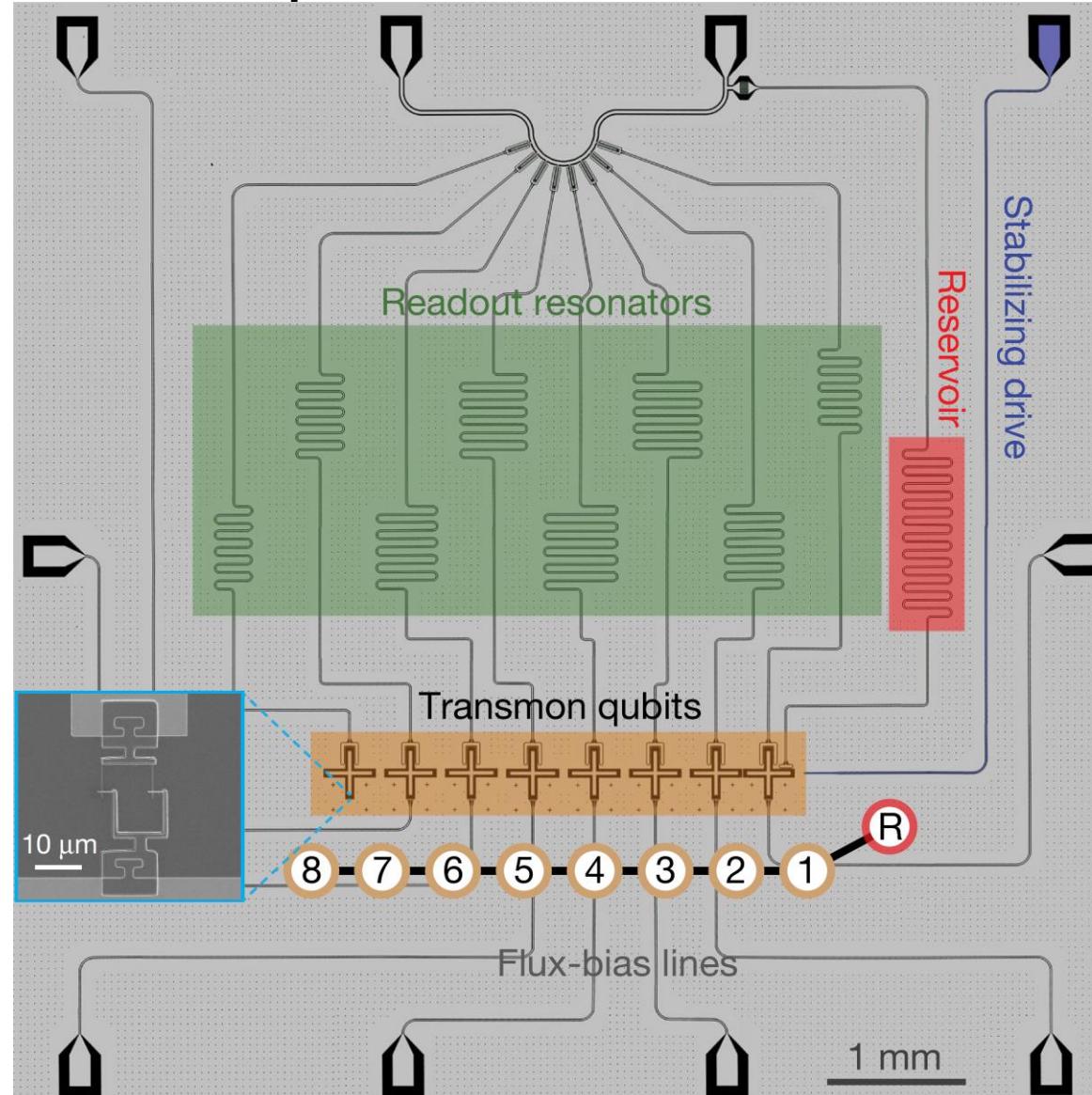
$$a |m\rangle = \sqrt{m} |m-1\rangle$$

## Qubit readout



# Experimental setup

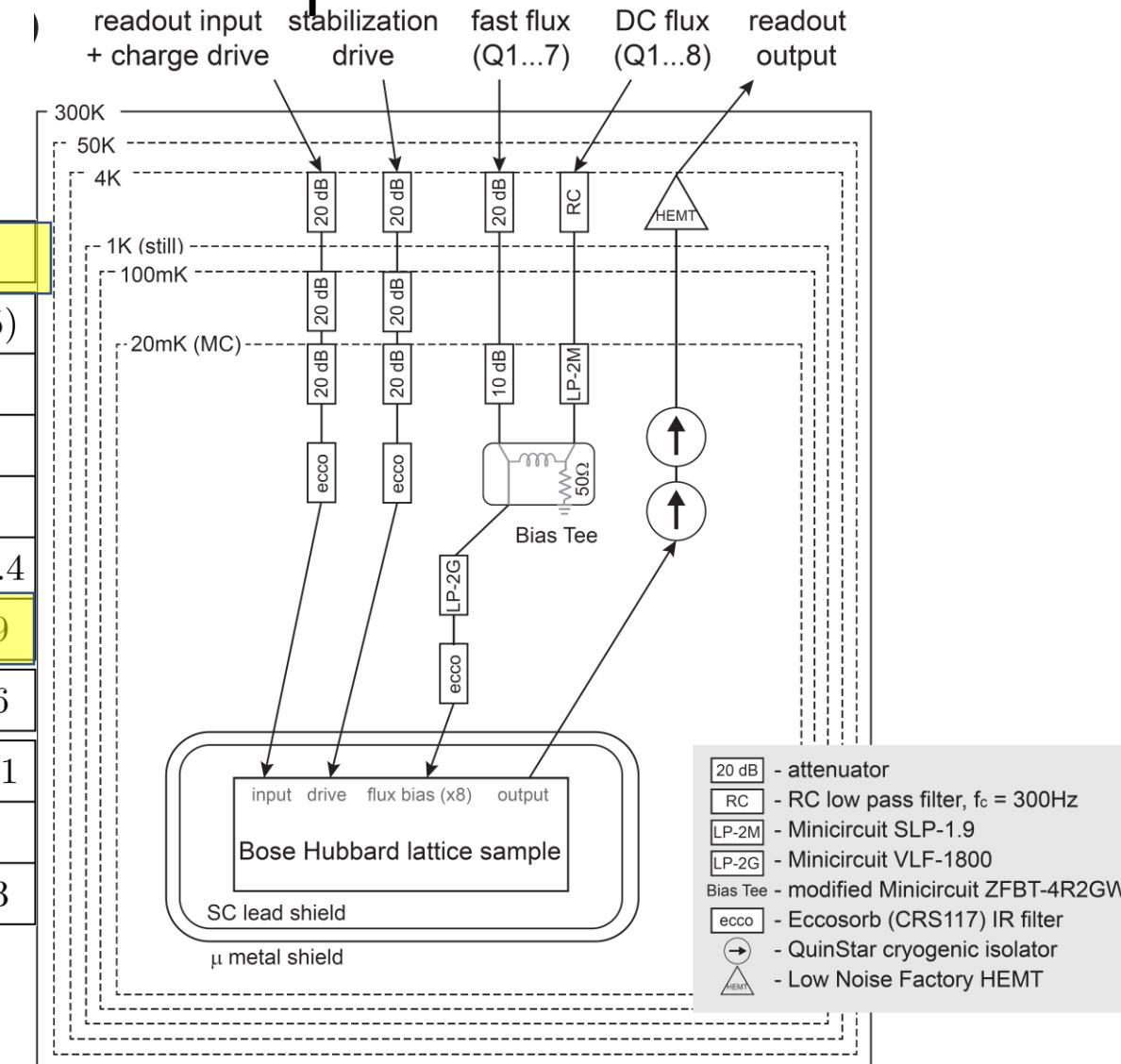
- Cooling with dilution refrigerator
- Radiation shields
- Transmon qubit: Aluminum josephson junctions
- Tuning of qubits: Flux-Bias lines and external DC-coil
- Qubit capacitative coupling (non neighbouring coupling is suppressed by an order of magnitude)
- Readout of qubits: Reflectance of input signal, while resonators are spectrally separated
- Stabilizing drive excites Q1



# Experimental setup

	$Q_1$	$Q_2$	$Q_3$	$Q_4$	$Q_5$	$Q_6$	$Q_7$	$Q_8$
$T_1$ ( $\mu$ s)	22(4)	19(4)	30(3)	40(3)	34(4)	42(3)	19(3)	36(5)
$\Gamma_1/2\pi$ (kHz)	7.2	8.4	5.3	4.0	4.7	3.8	8.4	4.4
$T_2^*$ ( $\mu$ s)	2 - 4	2 - 4	2 - 4	2 - 4	2 - 4	2 - 4	2 - 4	5
$\Gamma_d/2\pi$ (kHz)	40-80	40-80	40-80	40-80	40-80	40-80	40-80	30
$\alpha/2\pi$ (MHz)	-254.3	-258.6	-254.1	-160.0	-253.2	-247.7	-252.0	-252.4
$g_{i-1,i}/2\pi$ (MHz)	16.30	12.68	6.34	6.47	6.18	6.33	6.37	6.09
$n_{\text{th}}$	0.07	0.06	0.03	0.05	0.04	0.06	0.02	0.06
$\omega_{\text{read}}/2\pi$ (GHz)	6.474	6.367	6.467	6.346	6.430	6.310	6.381	6.261
$g_{\text{read}}/2\pi$ (MHz)	70	69	70	66	70	70	70	68
$\kappa_{\text{read}}/2\pi$ (MHz)	0.50	0.40	0.44	0.43	0.40	0.44	0.42	0.33

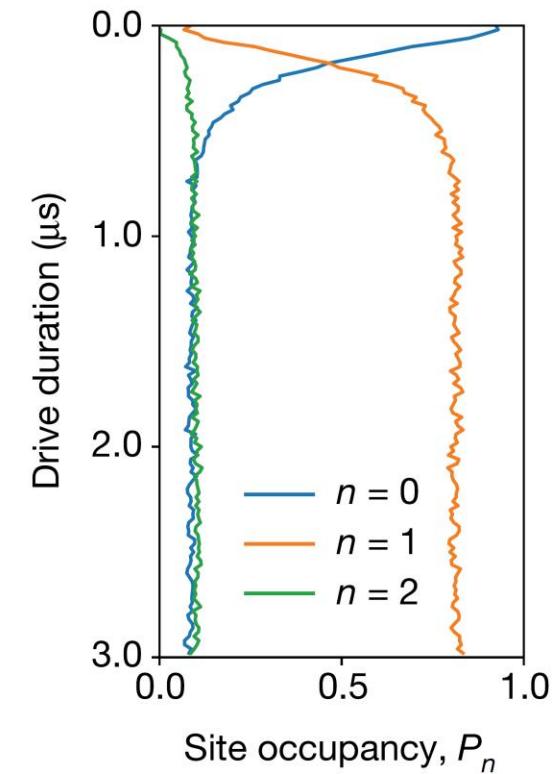
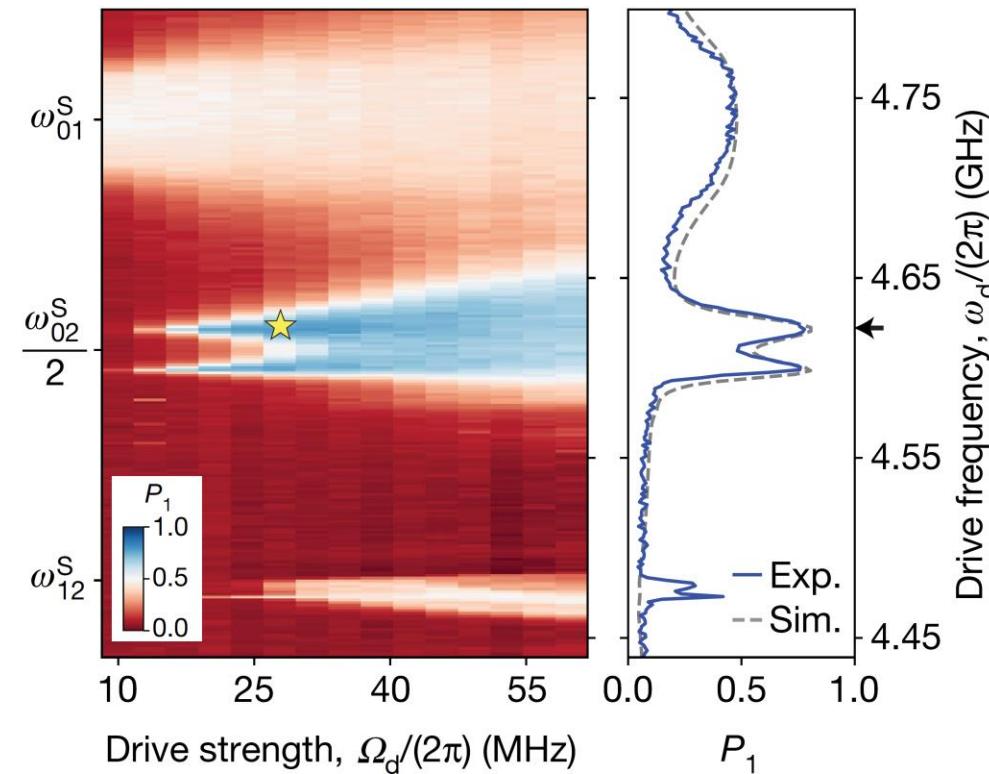
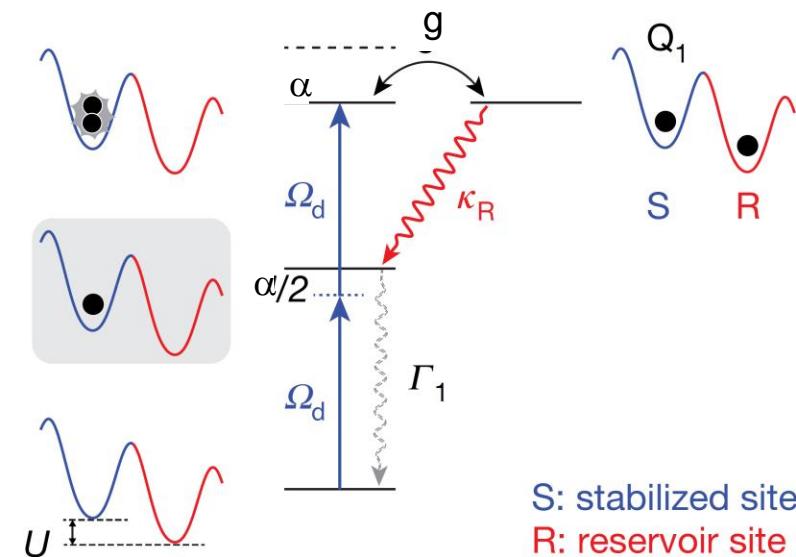
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# One Transmon scheme

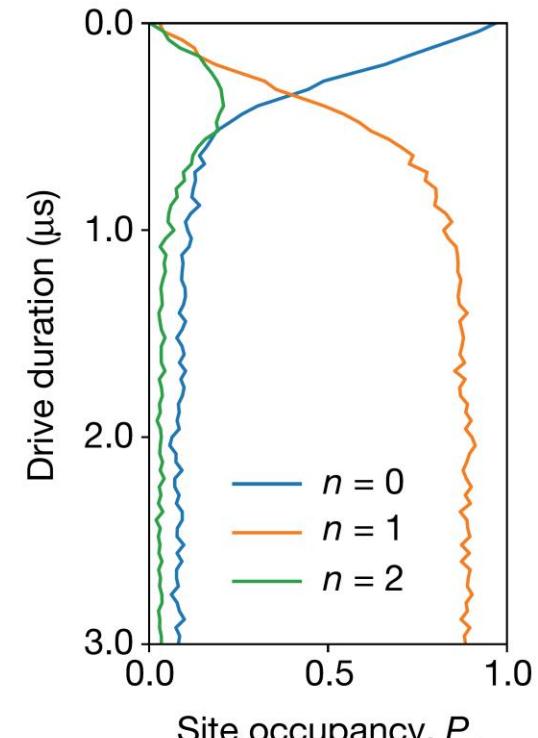
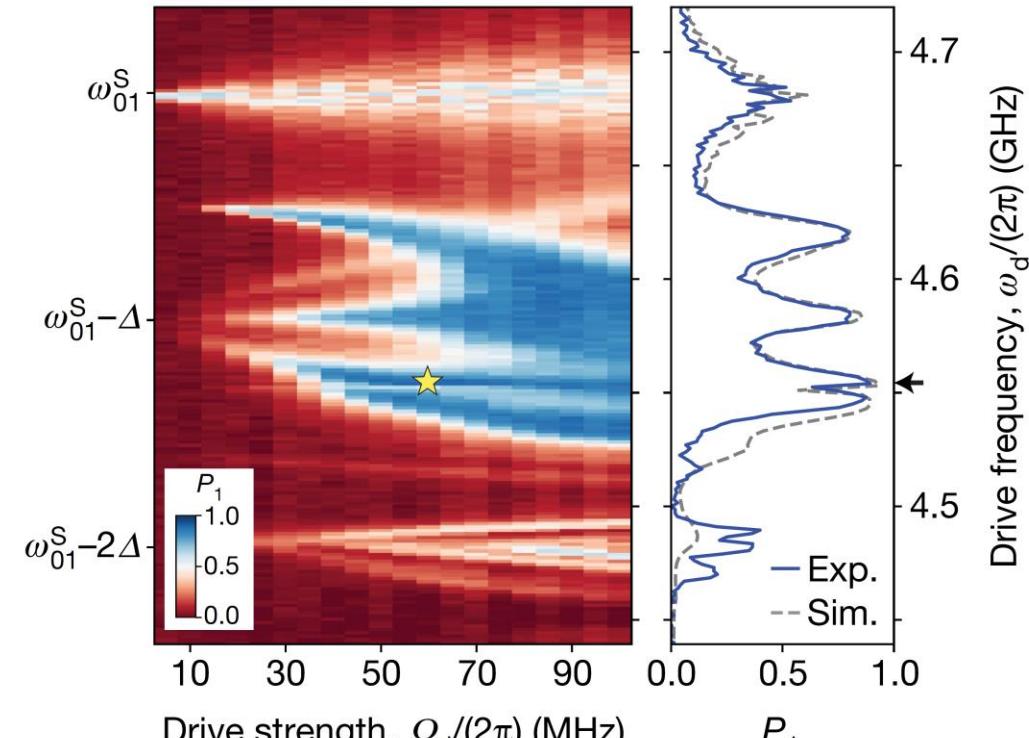
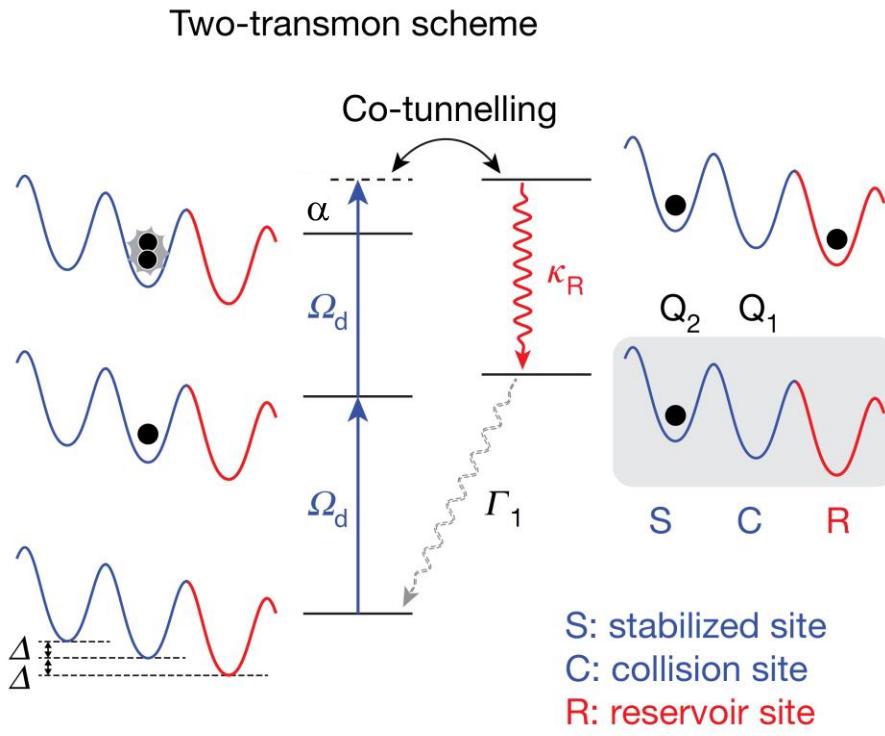
- Two photon transition: Decay into one photon state
- Excitation at 0->1 energy gives a max occupation of 0.5 (two level laser)
- Low Drive Strength: Single photon decay too high
- High Drive Strength: Lossy resonator decay too small

One-transmon scheme



# Two Transmon scheme

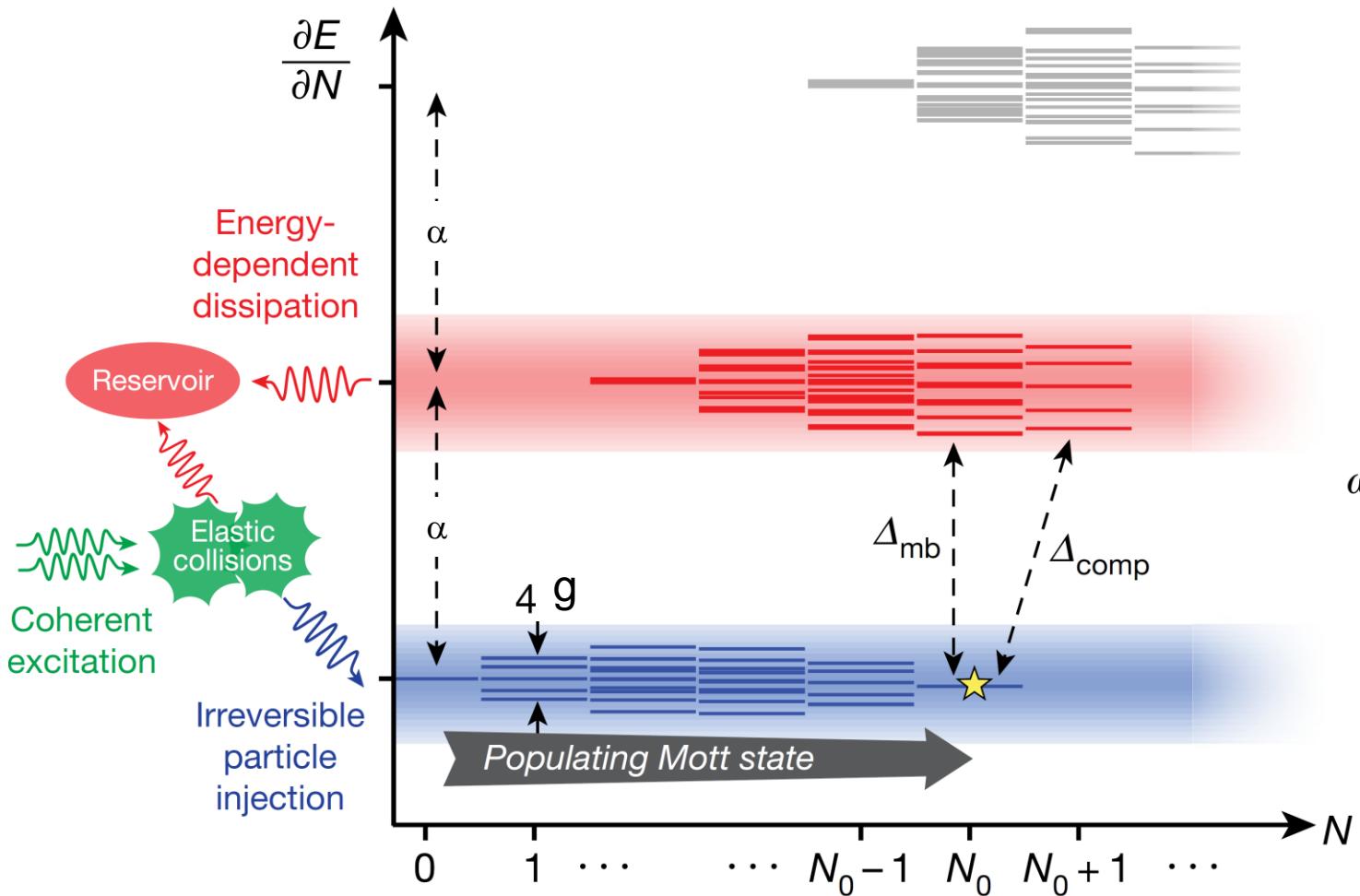
- Excitation with energy corresponding to 0->1 transition of collision state
- Elastic collision of two photons, one into S, the other into R (seperated by  $2\Delta$ )
- Photon insertion irreversible:  $\Delta=2\pi 100\text{MHz}$



# Mott insulator

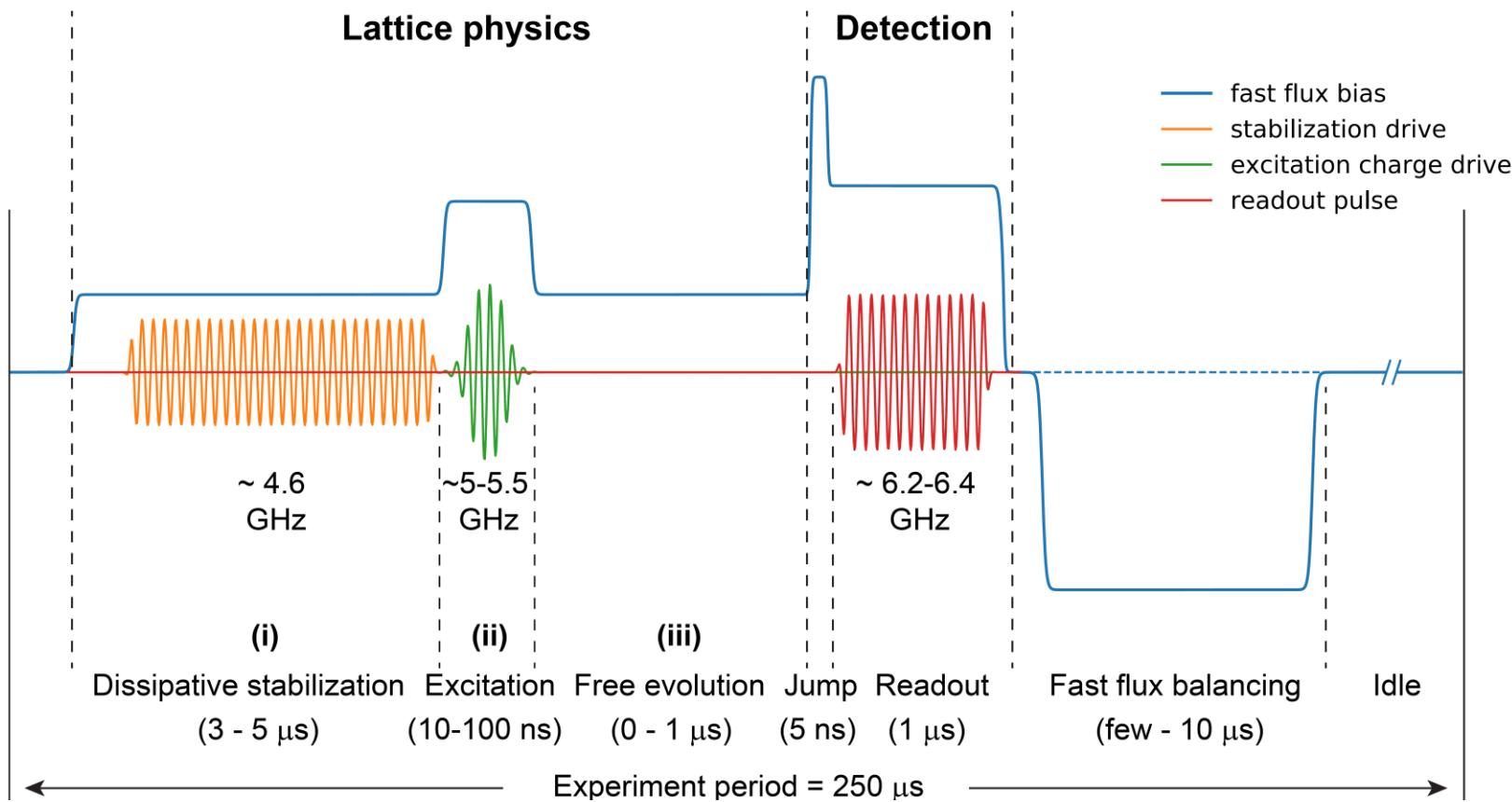
$$H_{BH} = \sum_{\langle i,j \rangle} g_{i,j} a_i^\dagger a_j + \frac{\alpha}{2} \sum_i n_i(n_i - 1) + \sum_i \hbar\omega_p n_i$$

- Incompressible state of N photons
- Many-body Gap allows specific state of the system
- Varying energy in blue or red band due to interaction g
- Mott insulator: Insulator which should be a conductor according to band structure (odd (1) number of photons per lattice site)



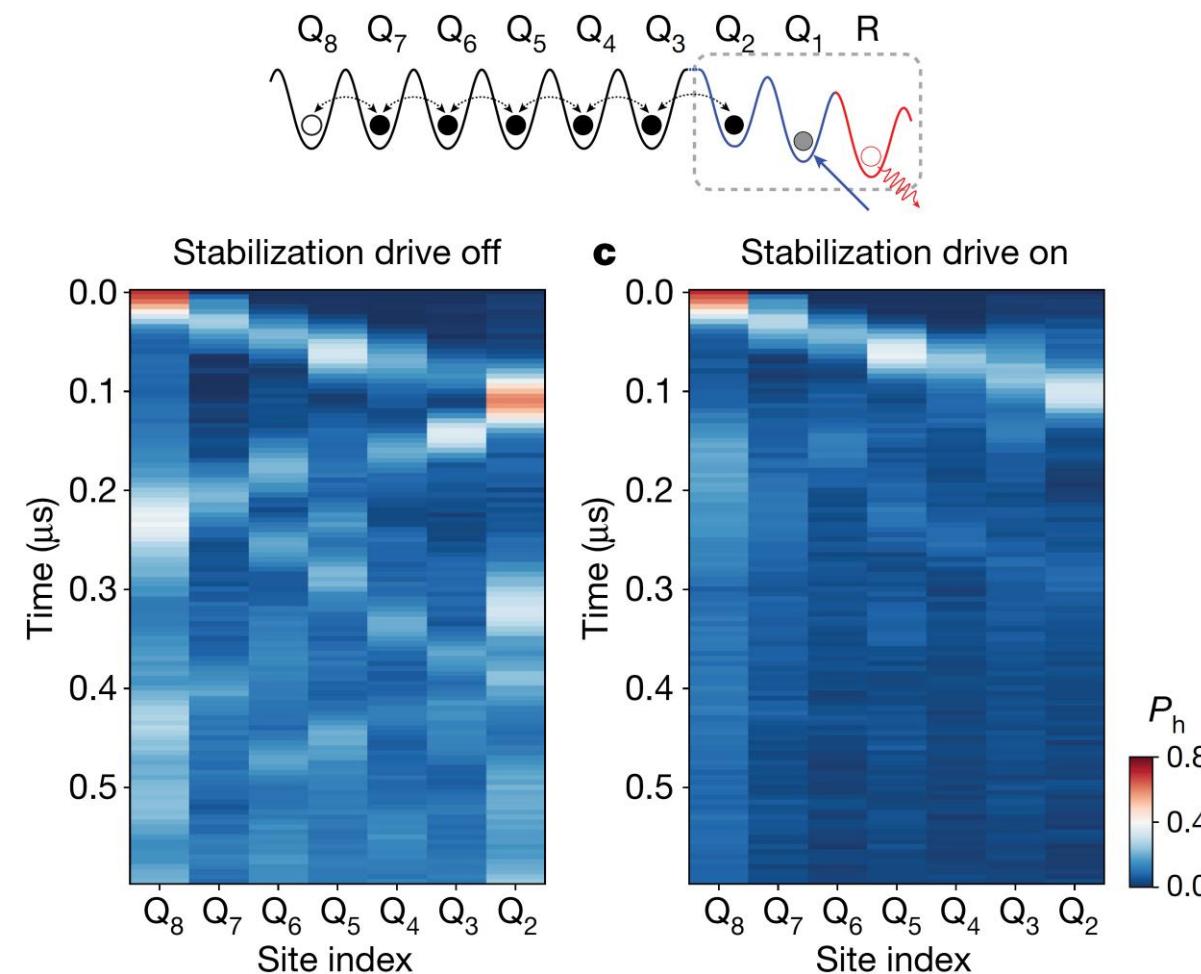
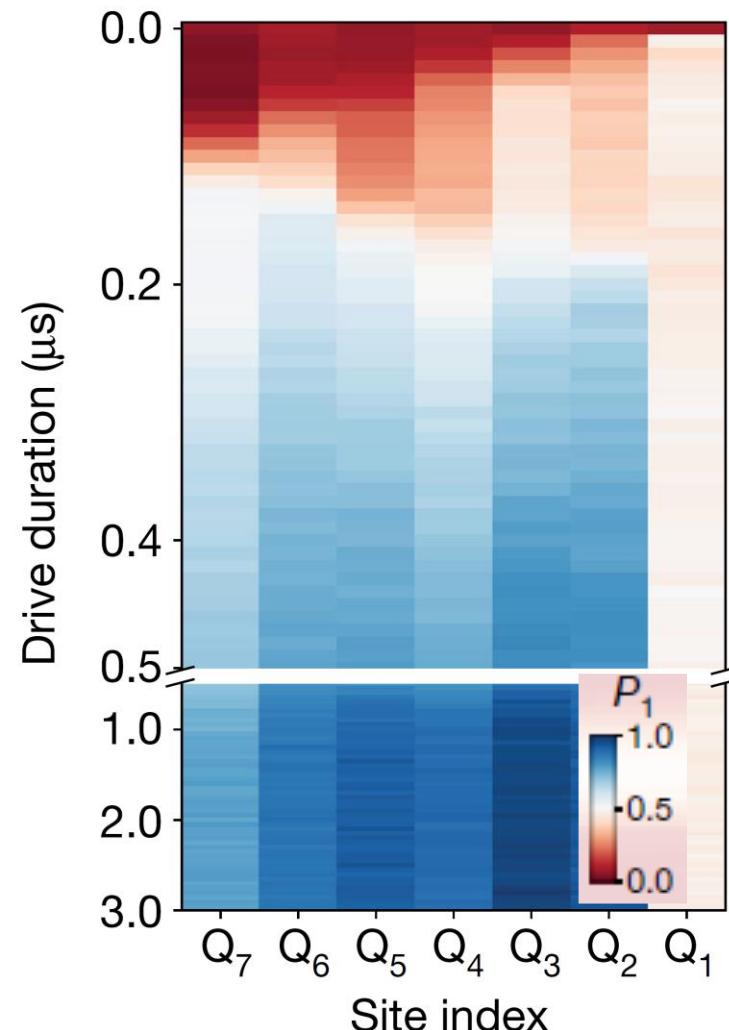
# Experimental sequence

- Fast flux bias for ns accuracy tuning
- Detuning to freeze the current state
- Idle: Time before new sequence in order to decay back to the ground state



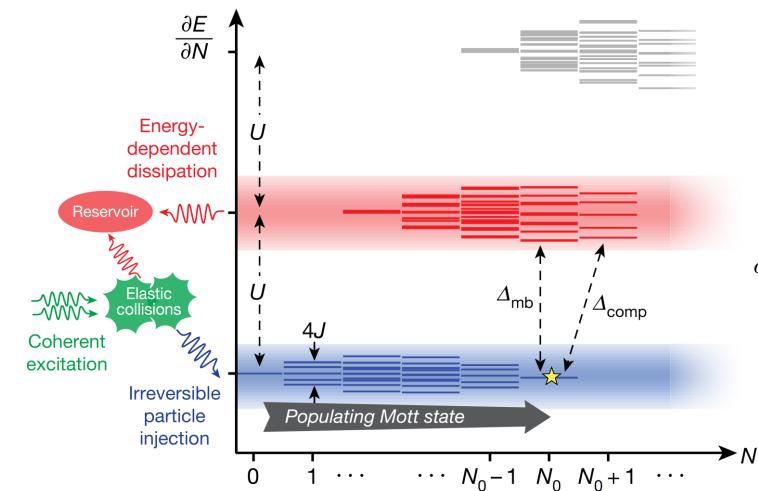
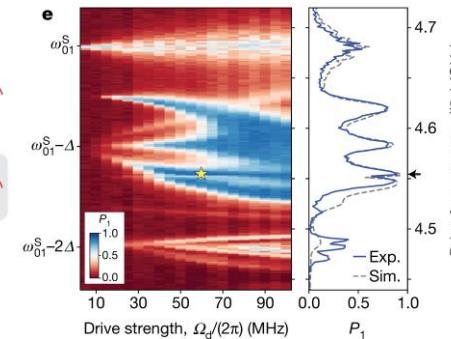
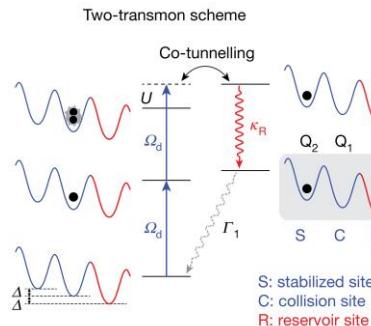
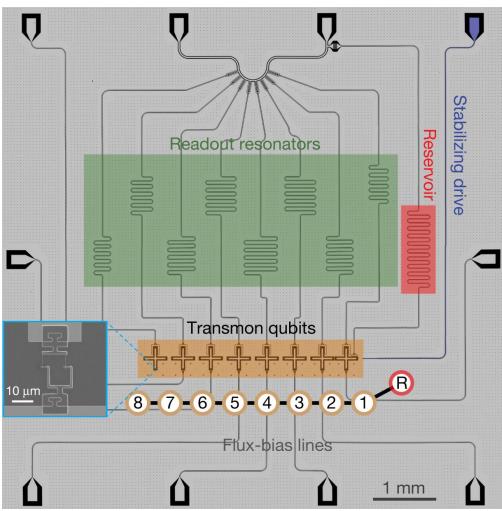
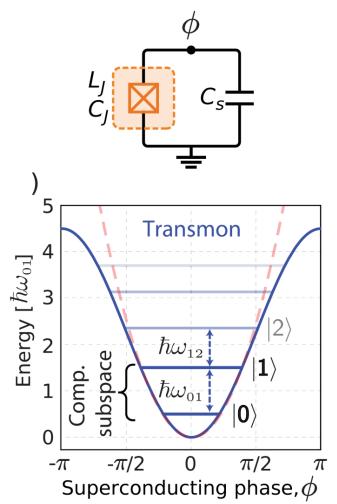
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# Stabilization and hole dynamics of the lattice



- Hole dynamics of the lattice:
- $Q_8$  is detuned during stabilization
  - Tuning  $Q_8$  back to resonance shows dynamic hole behaviour

# Summary



# References

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